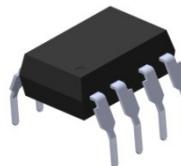
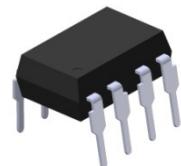


# 8 PIN DIP DUAL CHANNEL HIGH SPEED 1Mbit/s TRANSISTOR PHOTOCOUPLER

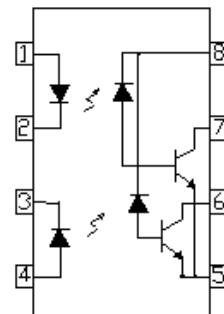
EL253X series

## Features

- High speed 1Mbit/s
- High isolation voltage between input and output ( $V_{iso}=5000$  Vrms )
- Guaranteed performance from 0 °C to 70 °C
- Wide operating temperature range of -40 °C to 85 °C
- Pb free and RoHS compliant
- UL approved (No. 214129)
- VDE approved (No. 132249)
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved
- CSA approved
- CQC approved



Schematic



## Description

The EL2530 and EL2531 dual channel devices each consist of an infrared emitting diode, optically coupled to a high speed photo detector transistor. A separate connection for the photodiode bias and output-transistor collector increase the speed by several orders of magnitude over conventional phototransistor couplers by reducing the base-collector capacitance of the input transistor.

The devices are packaged in an 8-pin DIP package and available in wide-lead spacing and SMD option.

## Applications

- Line receivers
- Telecommunication equipments
- Power transistor isolation in motor drives
- Replacement for low speed phototransistor photo couplers
- Feedback loop in switch-mode power supplies
- Home appliances
- High speed logic ground isolation

## Pin Configuration

1. Anode
2. Cathode
3. Cathode
4. Anode
5. Gnd
6. Vout2
7. Vout1
8. VCC

# 8 PIN DIP DUAL CHANNEL HIGH SPEED 1Mbit/s TRANSISTOR PHOTOCOUPLER

## EL253X series

### Absolute Maximum Ratings ( $T_a=25^\circ\text{C}$ )

Parameter		Symbol	Rating	Unit
Input	Forward current	$I_F$	25	mA
	Peak forward current (50% duty, 1ms P.W)	$I_{FP}$	50	mA
	Peak transient current ( $\leq 1\mu\text{s}$ P.W,300pps)	$I_{F\text{trans}}$	1	A
	Reverse voltage	$V_R$	5	V
	Power dissipation	$P_{IN}$	45	mW
Output	Power dissipation	$P_O$	35	mW
	Average Output current	$I_{O(\text{AVG})}$	8	mA
	Peak Output current	$I_{O(PK)}$	16	mA
	Output voltage	$V_O$	-0.5 to 20	V
	Supply voltage	$V_{CC}$	-0.5 to 30	V
Isolation voltage *1		$V_{ISO}$	5000	V rms
Operating temperature		$T_{OPR}$	-40 ~ +100	°C
Storage temperature		$T_{STG}$	-40 ~ +125	°C
Soldering temperature *2		$T_{SOL}$	260	°C

### Notes

\*1 AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1, 2, 3, 4 are shorted together, and pins 5, 6, 7, 8 are shorted together.

\*2 For 10 seconds.

# 8 PIN DIP DUAL CHANNEL HIGH SPEED 1Mbit/s TRANSISTOR PHOTOCOUPLED

EL253X series

## Electrical Characteristics ( $T_A=0$ to $70^\circ\text{C}$ unless specified otherwise)

### Input

Parameter	Symbol	Min.	Typ.*	Max.	Unit	Conditions
Forward voltage	$V_F$	-	1.45	1.8	V	$I_F = 16\text{mA}, T_A=25^\circ\text{C}$
Reverse Voltage	$V_R$	5.0	-	-	V	$I_R = 10\mu\text{A}$
Temperature coefficient of forward voltage	$V_F/T_A$	-	-1.9	-	mV/°C	$I_F = 16\text{mA}$
Input Capacitance	$C_{IN}$	-	60	-	pF	$V_F=0\text{V}, f=1\text{MHz}$

### Output

Parameter	Symbol	Min.	Typ.*	Max.	Unit	Conditions
Logic High Output Current	$I_{OH}$	-	0.001	0.5	$\mu\text{A}$	$I_F=0\text{mA}, V_O=V_{CC}=5.5\text{V}, T_A=25^\circ\text{C}$
		-	-	50		$I_F=0\text{mA}, V_O=V_{CC}=15\text{V}, T_A=25^\circ\text{C}$
Logic Low Supply Current	$I_{CCL}$	-	140	400	$\mu\text{A}$	$I_{F1}=I_{F2}16\text{mA}, V_O=\text{Open}, V_{CC}=15\text{V}$
Logic High Supply Current	$I_{CCH}$	-	0.01	1	$\mu\text{A}$	$I_F=0\text{mA}, V_O=\text{Open}, V_{CC}=15\text{V}, T_A=25^\circ\text{C}$
		-	-	4		$I_F=0\text{mA}, V_O=\text{Open}, V_{CC}=15\text{V}$

\* Typical values at  $T_A = 25^\circ\text{C}$

# 8 PIN DIP DUAL CHANNEL HIGH SPEED 1Mbit/s TRANSISTOR PHOTOCOUPLED

**EL253X series**

## Transfer Characteristics ( $T_A=0$ to $70^\circ\text{C}$ unless specified otherwise)

Parameter		Symbol	Min.	Typ.*	Max.	Unit	Conditions
Current Transfer Ratio	EL2530	CTR	7	-	50	% $I_F = 16\text{mA}, V_O = 0.4\text{V}, V_{CC} = 4.5\text{V}, T_A = 25^\circ\text{C}$	
	EL2531		19	-	50		
	EL2530		5	-	-		
	EL2531		15	-	-		
Logic Low Output Voltage	EL2530	V <sub>OL</sub>	-	0.18	0.5	V $I_F = 16\text{mA}, I_O = 1.1\text{mA}, V_{CC} = 4.5\text{V}, T_A = 25^\circ\text{C}$	
	EL2531		-	0.25	0.5		
	EL2530		-	-	0.5		
	EL2531		-	-	0.5		

## Switching Characteristics ( $T_A=0$ to $70^\circ\text{C}$ unless specified otherwise, $I_F=16\text{mA}$ , $V_{CC}=5\text{V}$ )

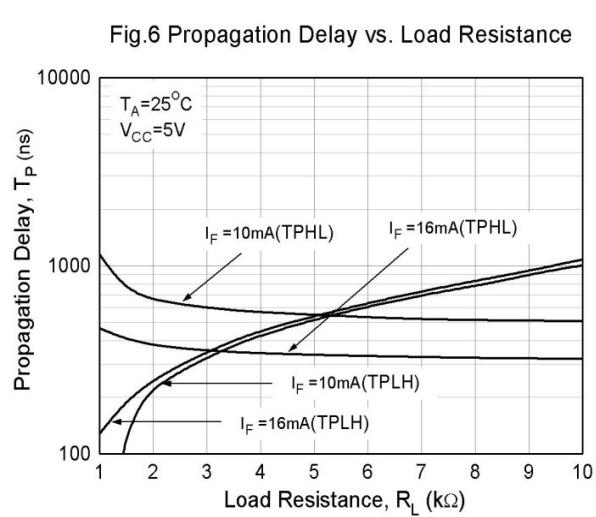
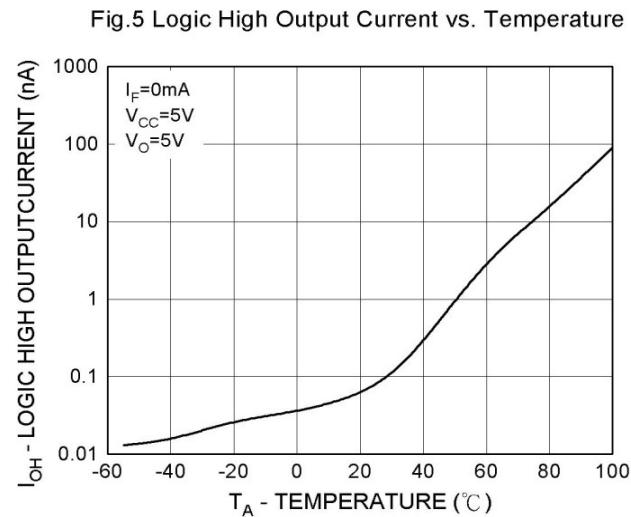
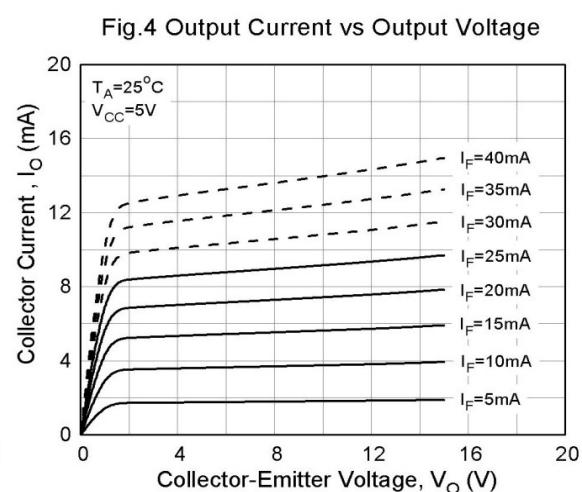
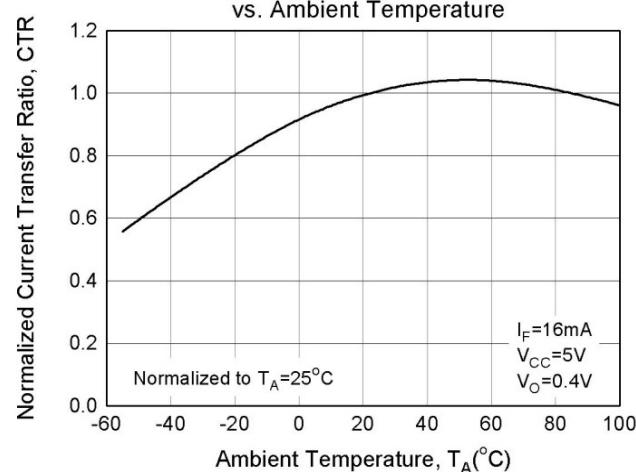
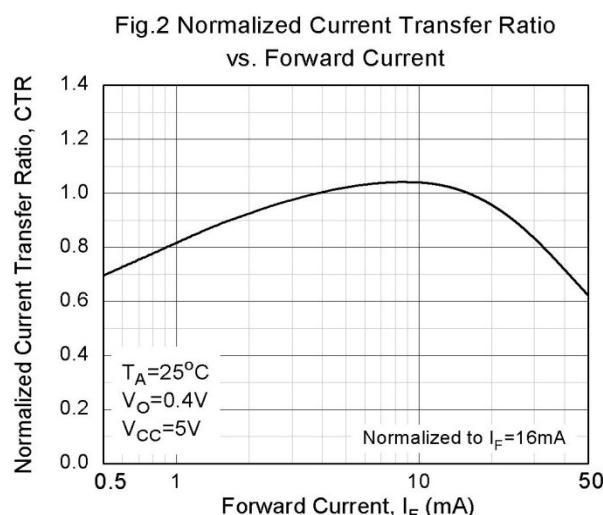
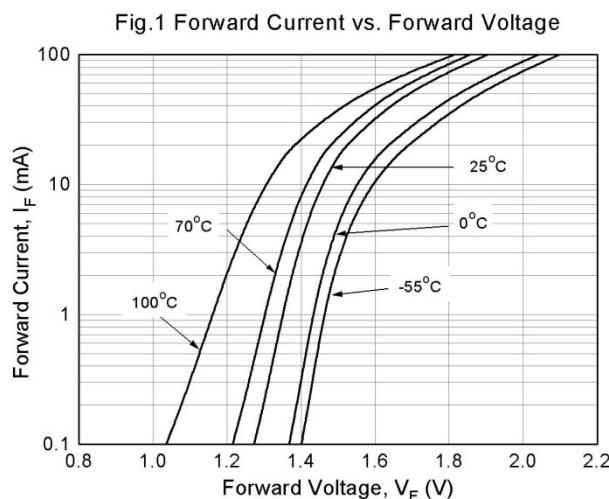
Parameter		Symbol	Min.	Typ.*	Max.	Unit	Conditions
Propagation Delay Time to Logic Low (Fig.8)	EL2530	t <sub>PHL</sub>	-	0.35	1.5	μs $R_L = 4.1\text{K}\Omega, T_A = 25^\circ\text{C}$	
	EL2531		-	-	2.0		
	EL2530		-	0.35	0.8		
	EL2531		-	-	1.0		
Propagation Delay Time to Logic High (Fig.8)	EL2530	t <sub>PLH</sub>	-	0.5	1.5	μs $R_L = 4.1\text{K}\Omega, T_A = 25^\circ\text{C}$	
	EL2531		-	-	2.0		
	EL2530		-	0.3	0.8		
	EL2531		-	-	1.0		
Common Mode Transient Immunity at Logic High (Fig.9) <sup>3</sup>	EL2530	CM <sub>H</sub>	1,000	10,000	-	V/μs $I_F = 0\text{mA}, V_{CM} = 10\text{Vp-p}, R_L = 4.1\text{K}\Omega, T_A = 25^\circ\text{C}$	
	EL2531		1,000	10,000	-		
Common Mode Transient Immunity at Logic Low (Fig.9) <sup>3</sup>	EL2530	CM <sub>L</sub>	1,000	10,000	-	V/μs $I_F = 16\text{mA}, V_{CM} = 10\text{Vp-p}, R_L = 4.1\text{K}\Omega, T_A = 25^\circ\text{C}$	
	EL2531		1,000	10,000	-		

\* Typical values at  $T_A = 25^\circ\text{C}$

# 8 PIN DIP DUAL CHANNEL HIGH SPEED 1Mbit/s TRANSISTOR PHOTOCOUPLED

**EL253X series**

## Typical Performance Curves



# 8 PIN DIP DUAL CHANNEL HIGH SPEED 1Mbit/s TRANSISTOR PHOTOCOUPLED

EL253X series

Fig.7 Propagation Delay vs. Temperature

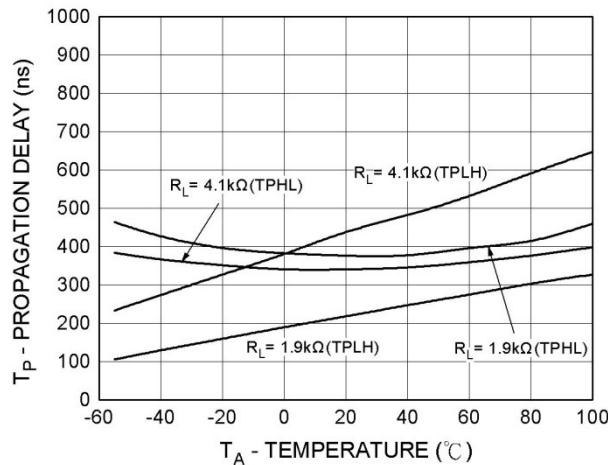


Figure 8 Switching Time Test Circuit & Waveform

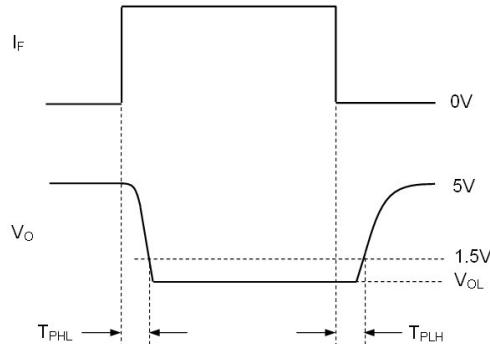
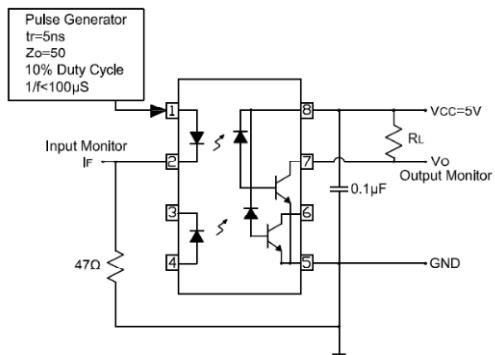
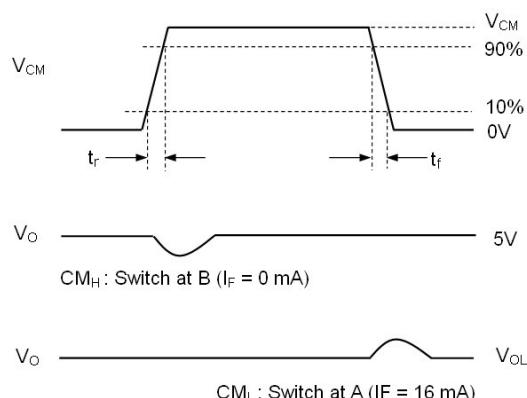
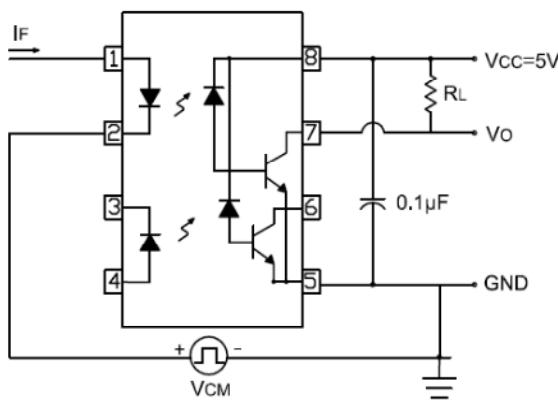


Figure 9 Transient Immunity Test Circuit & Waveform



## Note:

\*3 Common mode transient immunity in logic high level is the maximum tolerable (positive)  $dV_{cm}/dt$  on the leading edge of the common mode pulse signal  $V_{CM}$ , to assure that the output will remain in a logic high state (i.e.,  $V_O > 2.0\text{V}$ ).

Common mode transient immunity in logic low level is the maximum tolerable (negative)  $dV_{cm}/dt$  on the trailing edge of the common mode pulse signal,  $V_{CM}$ , to assure that the output will remain in a logic low state (i.e.,  $V_O < 0.8\text{V}$ ).

**8 PIN DIP DUAL CHANNEL HIGH SPEED  
1Mbit/s TRANSISTOR PHOTOCOUPLER****EL253X series****Order Information****Part Number****EL253XY(Z)-V****Note**

X = Part no. (0 or 1)

Y = Lead form option (S, S1, M or none)

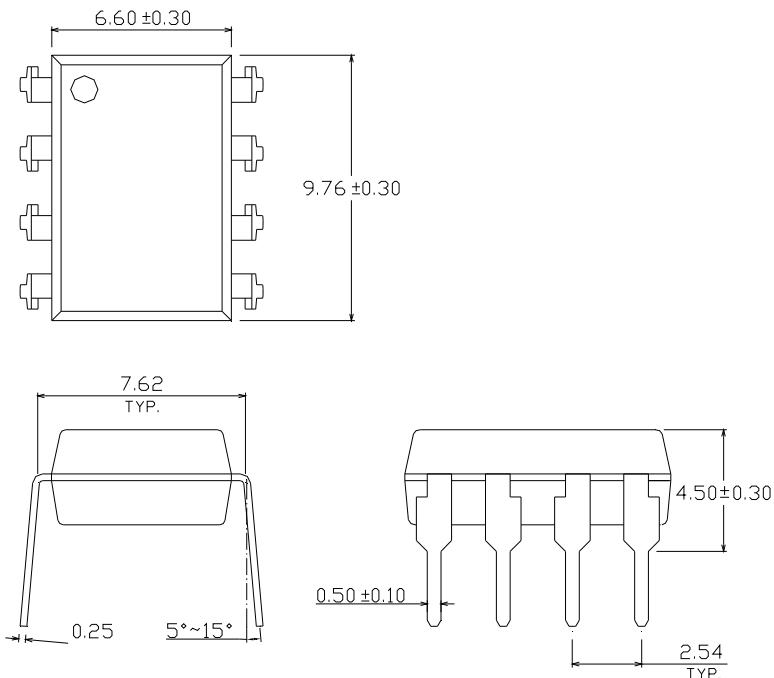
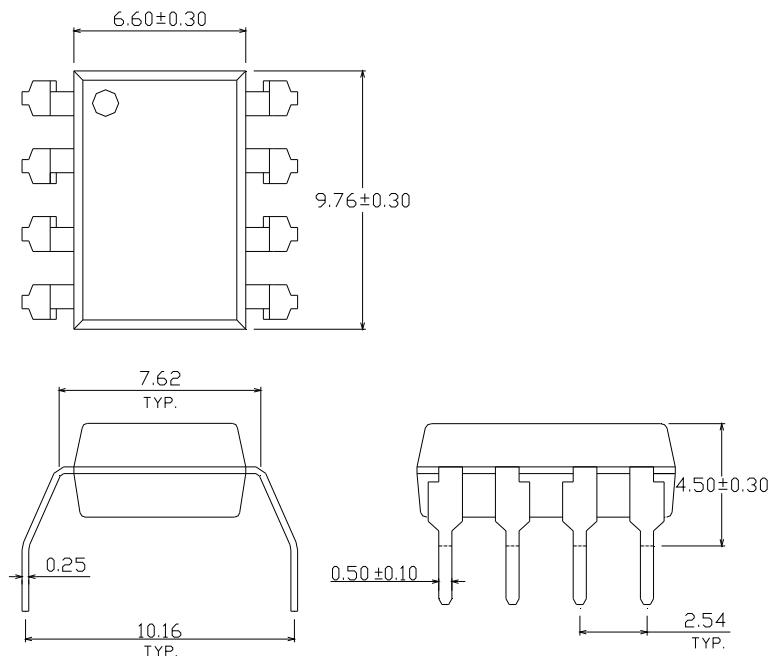
Z = Tape and reel option (TA, TB or none)

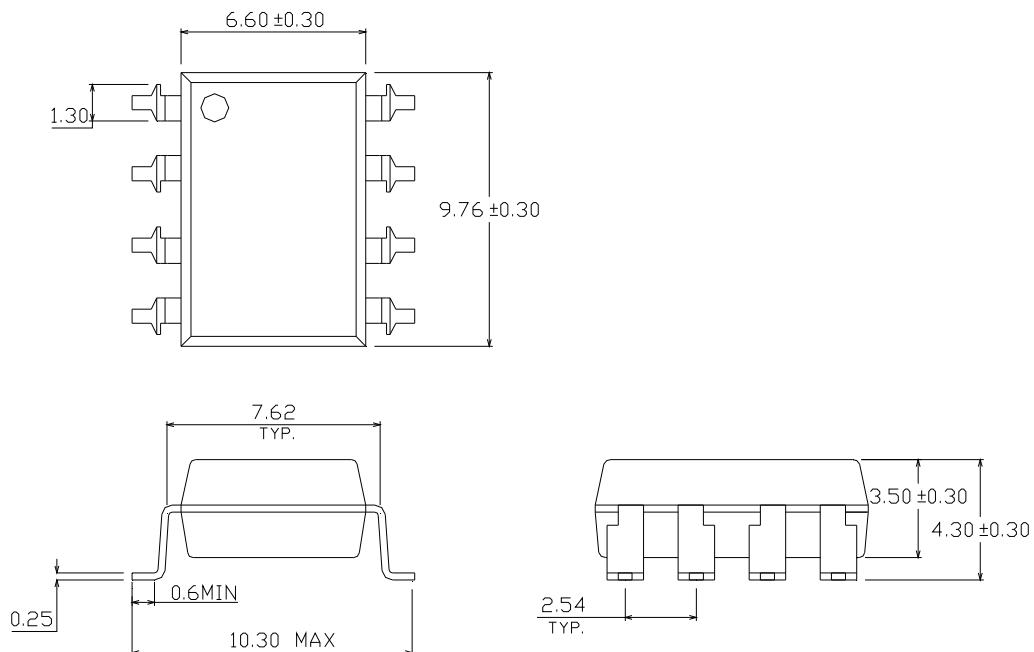
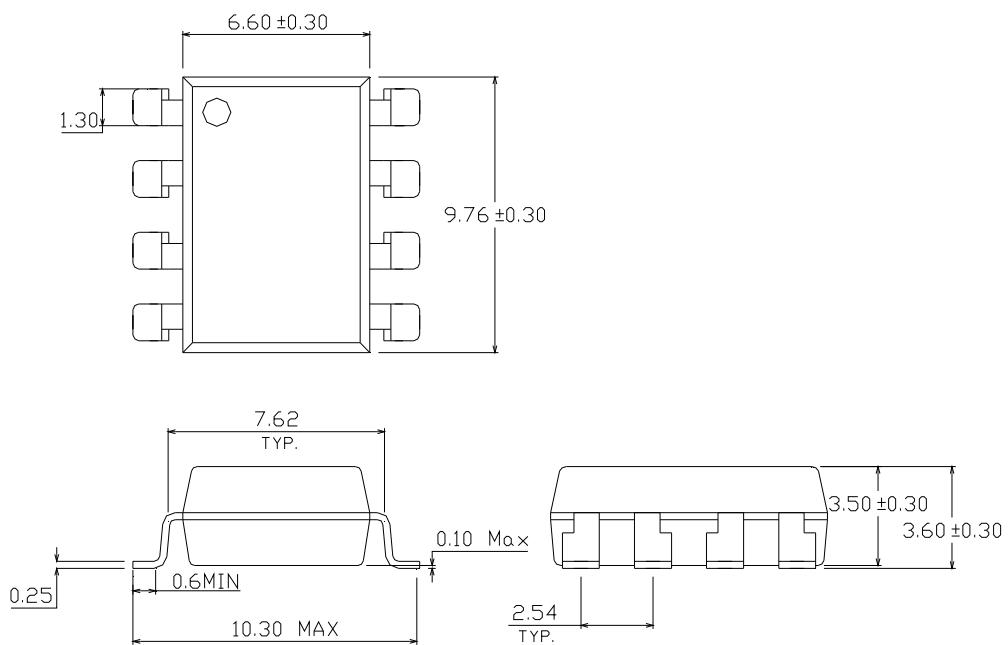
V = VDE (optional)

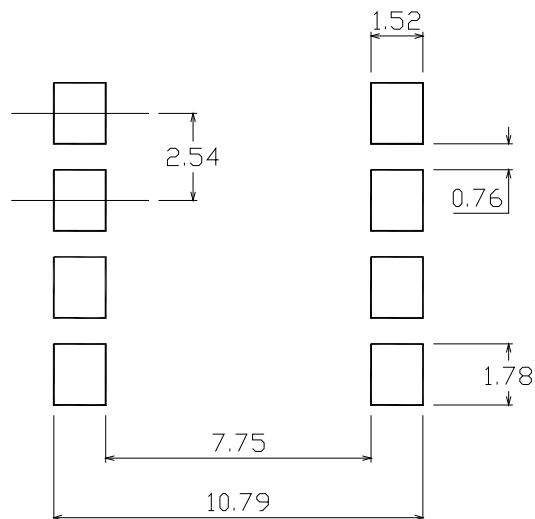
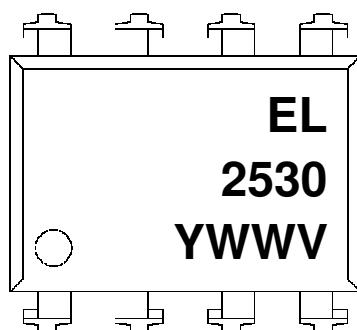
Option	Description	Packing quantity
None	Standard DIP-8	45 units per tube
M	Wide lead bend (0.4 inch spacing)	45 units per tube
S (TA)	Surface mount lead form + TA tape & reel option	1000 units per reel
S (TB)	Surface mount lead form + TB tape & reel option	1000 units per reel
S1 (TA)	Surface mount lead form (low profile) + TA tape & reel option	1000 units per reel
S1 (TB)	Surface mount lead form (low profile) + TB tape & reel option	1000 units per reel

**Package Drawing**

(Dimensions in mm)

**Standard DIP Type****Option M Type**

**8 PIN DIP DUAL CHANNEL HIGH SPEED  
1Mbit/s TRANSISTOR PHOTOCOUPLER****EL253X series****Option S Type****Option S1 Type**

**Recommended pad layout for surface mount leadform****Device Marking****Notes**

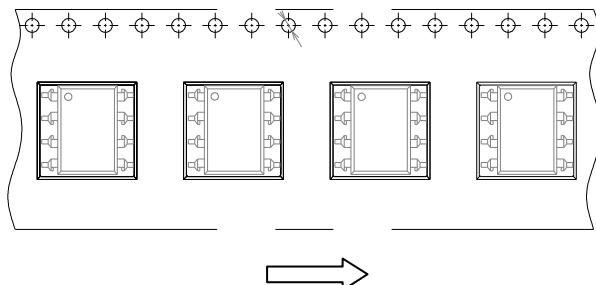
- 2530      denotes Device Number  
Y      denotes 1 digit Year code  
WW      denotes 2 digit Week code  
V      denotes VDE (optional)

# 8 PIN DIP DUAL CHANNEL HIGH SPEED 1Mbit/s TRANSISTOR PHOTOCOUPLER

EL253X series

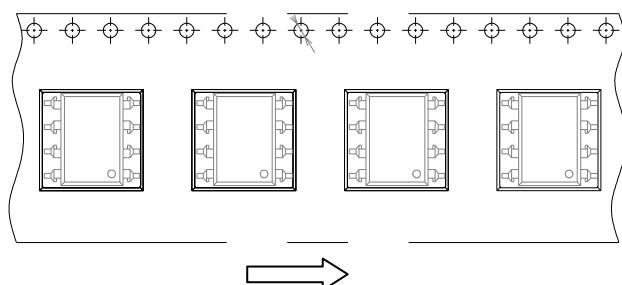
## Tape & Reel Packing Specifications

Option TA



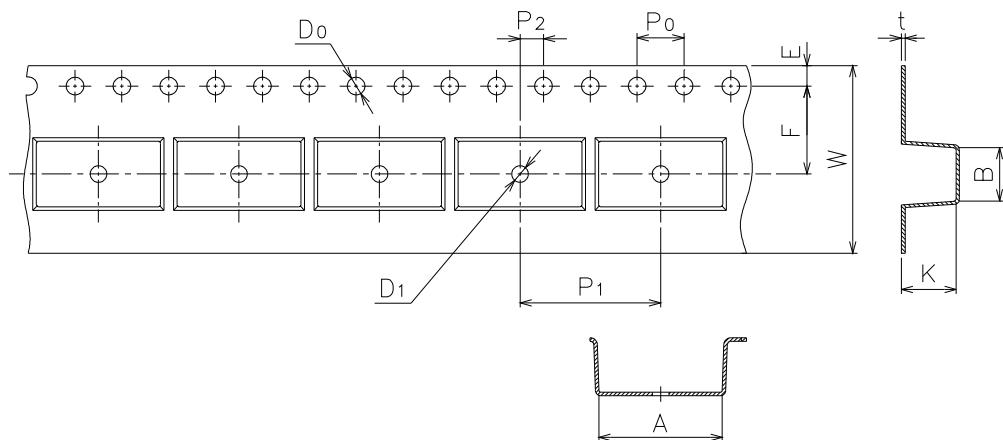
Direction of feed from reel

Option TB

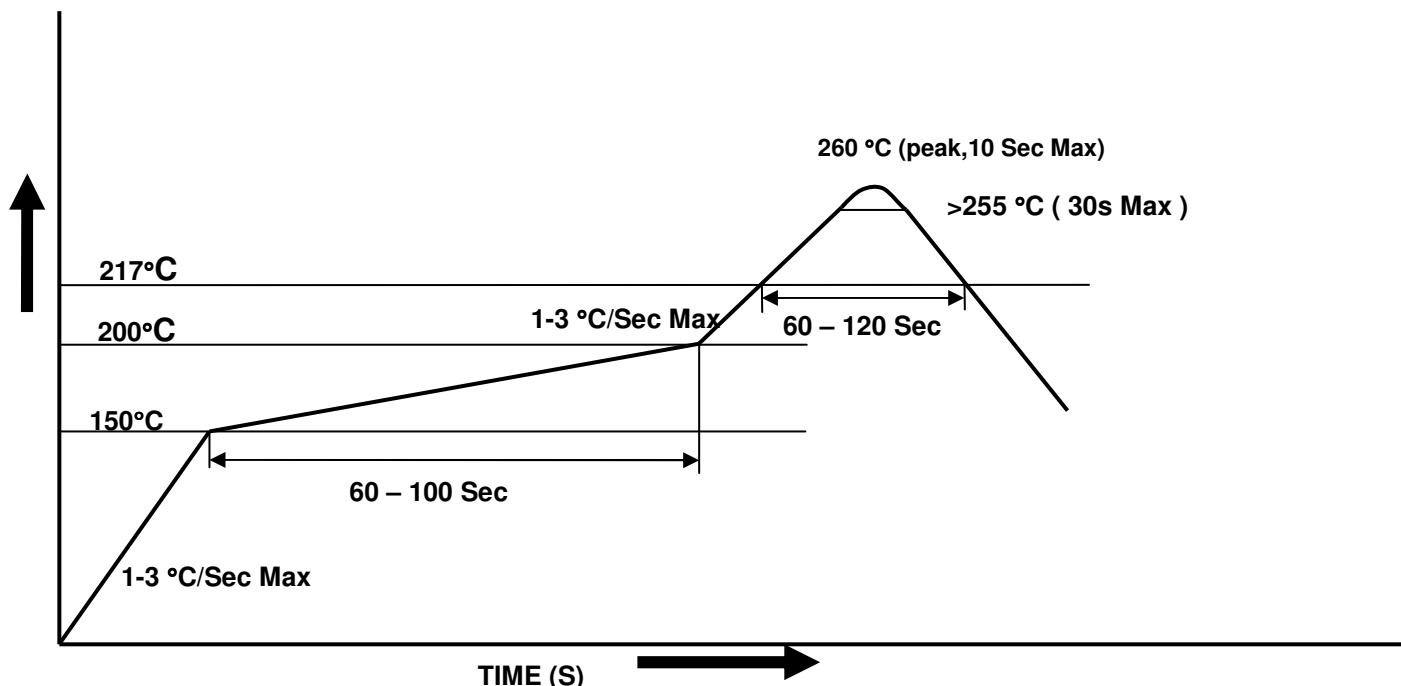


Direction of feed from reel

## Tape dimensions



Dimension No.	<b>A</b>	<b>B</b>	<b>D<sub>0</sub></b>	<b>D<sub>1</sub></b>	<b>E</b>	<b>F</b>
Dimension(mm)	$10.4 \pm 0.1$	$10.0 \pm 0.1$	$1.5 \pm 0.1$	$1.5 \pm 0.1$	$1.75 \pm 0.1$	$7.5 \pm 0.1$
Dimension No.	<b>P<sub>0</sub></b>	<b>P<sub>1</sub></b>	<b>P<sub>2</sub></b>	<b>t</b>	<b>W</b>	<b>K</b>
Dimension(mm)	$4.0 \pm 0.1$	$12.0 \pm 0.1$	$2.0 \pm 0.1$	$0.4 \pm 0.1$	$16.0 +0.3/-0.1$	$4.5 \pm 0.1$

**Solder Reflow Temperature Profile**

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[TLP2361\(E\(T](#) [TLP2366\(E\(T](#) [TLP2366\(TPL,E](#) [TLP2368\(TPL,E\(T](#) [TLP521-2XGB](#) [TLP621-2XGB](#) [JANTXV4N24U](#) [8102802PC](#) [5962-](#)  
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[TLP2355\(TPL,E](#) [TLP2391\(E\(T](#) [TLP521-4GR](#) [TLP521-4XGB](#) [TLP621XSM](#) [IS281-4GB](#) [IS2805-4](#)